

CH424/CH424N

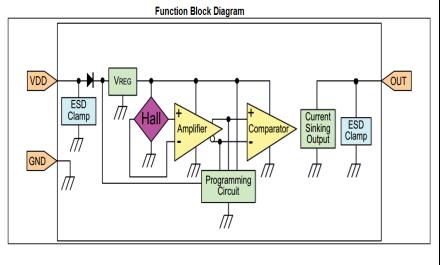
PACKAGE

Automotive Product Group

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#### FEATURES and FUNCTIONAL DIAGRAM

- Enhanced sensitivity: will operate from only 30 Gauss typical, at 25°C allowing the use of smaller, potentially lower-cost magnets or wider air gaps
- Subminiature, SOT-23-3L(CH424S/CH424NS) or SOT-89-3L(CH424E/CH424NE) surface mount package supplied on tape and reel allows for a compact design with automated component placement, helping to reduce manufacturing costs
- Small, leaded, flat, TO-92S package (CH424T/CH424NT) • allows for a compact PCB layout
- Bipolar latching magnetics respond to alternating North and • South poles, making these products well-suited for accurate speed sensing and RPM (revolutions per minute) measurement
- Wide operating voltage range of 3.3V to 30V makes these sensors useable in a wide range of applications
- Built-in reverse voltage capability enhances the protection of • the sensor and the circuits with which it is used
- Robust design: will operate up to 150 °C •
- RoHS-compliant material meets directive 2011/65/EU



## TO-92S SOT-23-3L SOT-89-3L APPLICATIONS Transportation Speed and RPM (revolutions per minute) sensing Tachometer, counter pickup Motor and fan control Electric window lift Convertible roof position Automotive transmission position Industrial Speed and RPM sensing Tachometer, counter pickup

- Flow-rate sensing
- Brushless dc (direct current) motor commutation
- Motor and fan control
- Robotics control
- Medical
- Motor assemblies
- Medication dispense control

## DESCRIPTION

The CH424 and CH424N are small, versatile digital Hall effect devices that are operated by the magnetic field from a permanent magnet or an electromagnet, designed to respond to alternating North and South poles.

These bipolar latching sensor ICs have enhanced sensitivity, which often allows for the use of less expensive magnets.

These sensor ICs are available in three package styles, the CH424S/CH424NS in the subminiature SOT-23-3L surface mount package, the CH424E/CH424NE in the subminiature SOT-89-3L surface mount package, and the CH424T/CH424NT in the leaded, flat TO-92S package.

The CH424S/CH424NSc and CH424E/CH424NEc small size requires less PC board space, allowing it to be used in smaller assemblies. Its 3.3V capability allows for use in low voltage applications, promoting eneray efficiency.

The CH424S/CH424NS and CH424E/CH424NE are available on tape and reel; the CH424T/CH424NT is available in a bulk package (1000 units per bag).



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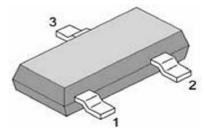
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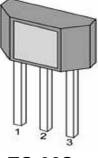
## 1. Product Family Members

Part Number	Marking ID	Description
CH424SR	C424	Bipolar latching, Hall-effect digital sensor IC, SOT-23-3L package, tape and reel packing (3000 units per reel)
CH424TB	C424	Bipolar latching, Hall-effect digital sensor IC, flat, TO-92S package, bulk packing (1000 units per bag)
CH424ER	C424	Bipolar latching, Hall-effect digital sensor IC, SOT-89-3L package, tape and reel packing (1000 units per reel)
CH424NSR	424N	Bipolar latching, Hall-effect digital sensor IC, SOT-23-3L package, tape and reel packing (3000 units per reel)
CH424NTB	424N	Bipolar latching, Hall-effect digital sensor IC, flat, TO-92S package, bulk packing (1000 units per bag)
CH424NER	424N	Bipolar latching, Hall-effect digital sensor IC, SOT-89-3L package, tape and reel packing (1000 units per reel)

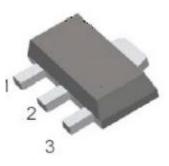
## 2. Pin Definitions and Descriptions

SOT-23-3L (S)	TO-92S (T)	SOT-89-3L (E)	Name	Туре	Function
1	1	1	VDD	Supply	Supply Voltage pin
2	3	3	OUT	Output	Open Collector Output pin
3	2	2	GND	Ground	Ground pin





**TO-92S** 



SOT-89-3L

#### 3. Absolute Maximum Ratings

SOT-23-3L

Parameter	Symbol	Min	Max	Units
Supply Voltage	V <sub>DD</sub>	-	40	V
VDD Reverse Voltage VDD	V <sub>RDD</sub>	-	-40	V
Supply Current	I <sub>DD</sub>	-	20	mA
Output Voltage	Vout	-0.3	40	V
Output Current	I <sub>OUT</sub>	-	25	mA
Operating Ambient Temperature	T <sub>A</sub>	-40	150	°C
Storage Temperature	Ts	-50	150	°C
Junction temperature	TJ	-50	165	°C
Magnetic Flux	В	No I	_imit	Gauss

Note: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolutemaximum- rated conditions for extended periods may affect device reliability.



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## 4. ESD Protections

Parameter	Value	Unit
All pins <sup>1)</sup>	+/-4000	V
All pins <sup>2)</sup>	+/-200	V
All pins <sup>3)</sup>	+/-750	V

1) HBM (human body mode, 100pF, 1.5 kohm ) according to MIL-STD-883H Method 3015.8

2) MM (Machine Mode C=200pF, R=0ô) according to JEDEC EIA/JESD22-A115

3) CDM (charged device mode) according to JEDEC EIA/JESD22-C101F

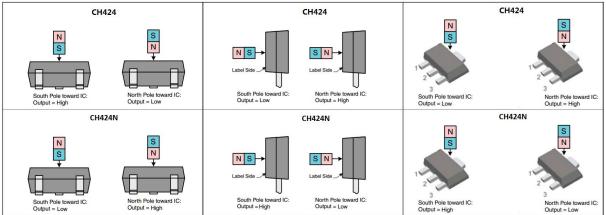
#### **5.** Function Description

The CH424/CH424N exhibits latch magnetic switching characteristics. Therefore, it requires both south and north poles to operate properly.

The device behaves as a latch with symmetric operating and release switching points (BOP=|BRP|). This means magnetic fields with equivalent strength and opposite direction drive the output high and low.

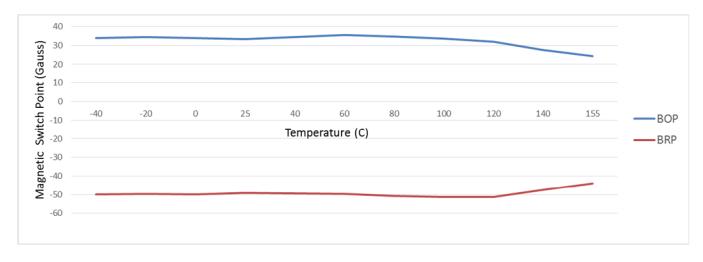
Removing the magnetic field (B 0) keeps the output in its previous state. This latching property defines the device as a magnetic memory.

A magnetic hysteresis BHYST keeps BOP and BRP separated by a minimal value. This hysteresis prevents output oscillation near the switching point.



#### 6. Magnetic Activation

## 7. Temperature Characteristics







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# 8. Parameters Specification (At 3.3V to 30V supply, 20mA load, TA= -40 °C to 150 °C except where otherwise specified.)

Symbol	Parameter	Test Condition	Min	Тур.	Max	Units
V <sub>DD</sub>	Supply voltage	-40 °C to 150 °C	3.3	-	30	V
I <sub>DD</sub>	Supply Current	$V_{DD} = 5V$	-	3.5	8	mA
V <sub>DSon</sub>	Output saturation voltage	at 20mA, Gauss >120	-	-	0.4	V
I <sub>OFF</sub>	Output Leakage Current	B<-120GS	-	-	10	uA
T <sub>R</sub>	Output rise time	V <sub>DD</sub> =12V at 25 °C C <sub>L</sub> = 20 pF	-	-	1.5	uS
T <sub>F</sub>	Output fall time	V <sub>DD</sub> =12V at 25 °C C <sub>L</sub> = 20 pF	-	-	1.5	uS
R <sub>TH</sub>	Thermal resistance: CH424S/CH424NS CH424T/CH424NT CH424E/ CH424NE	-	- - -	303 203 230	- - -	°C /W °C/W °C/W
B <sub>OP</sub>	CH424 Magnetic operating point	T <sub>A</sub> =25°C	5	30	55	Gauss
DOP	CH424N Magnetic operating point	T <sub>A</sub> =25°C	-55	-30	-5	Gauss
P	CH424 Magnetic release point	T <sub>A</sub> =25°C	-55	-30	-5	Gauss
B <sub>RP</sub>	CH424N Magnetic release point	T <sub>A</sub> =25°C	5	30	55	Gauss
B <sub>нүsт</sub>	CH424 Magnetic hysteresis window	T <sub>A</sub> =25°C  B <sub>OP</sub> -B <sub>RP</sub>	40	60	80	Gauss
DHYST	CH424N Magnetic hysteresis window	T <sub>A</sub> =25°C  B <sub>OP</sub> -B <sub>RP</sub>	40	60	80	Gauss
F <sub>SW</sub>	Maximum Switching Frequency				100	KHz
Т	Operating temperature	-	-40	-	150	°C
Ts	Storage temperature:	-	-40	-	150	°C

#### NOTICE

Bipolar Hall-effect sensor ICs may have an initial output in either the ON or OFF state if powered up with an applied magnetic field in the differential zone (applied magnetic field >Brp and <Bop). Cosemitech recommends allowing 10 µs for output voltage to stabilize after supply voltage has reached 5V.

#### NOTICE

The magnetic field strength (Gauss) required to cause the switch to change state (operate and release) will be as specified in the magnetic characteristics. To test the switch against the specified magnetic characteristics, the switch must be placed in a uniform magnetic field.



## CH424/CH424N

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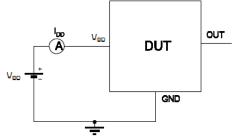
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#### 9. Test Conditions

Note: DUT=Device Under Test

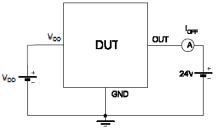
#### **Supply Current**



Note 1 - The supply current IDD represents the static supply current. OUT is left open during measurement

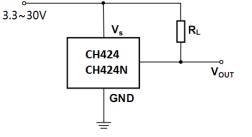
Note 2 - The device is put under magnetic field with B<BRP

#### **Output Leakage Current**

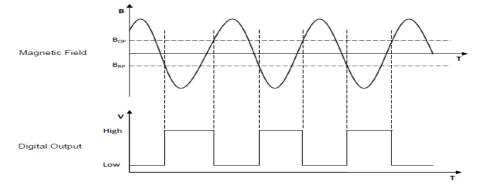


Note 1 - The device is put under magnetci field with B<BRP

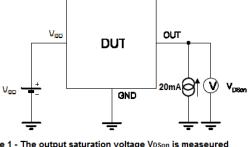
#### **10. Typical Application Circuit**



## 11. Typical Output Waveform (The CH424 TO-92S package as an example )



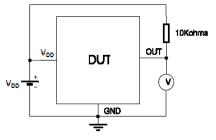
## **Output Saturation Voltage**



Note 1 - The output saturation voltage VDSon is measeured at VDD=3.8V and VDD=24V

Note 2 - The device is put under magnetic field with B>Bop

#### **Magenetic Thresholds**



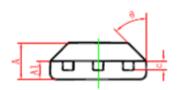
- Note 1 BOP is determined by putting the device under magnetic field swept from BRPmin up to BOPmax until the output is switched on.
- Note 2 BRP is determined by putting the device under magnetic field swept from BOPmax down to BRPmin until the output is switched off.

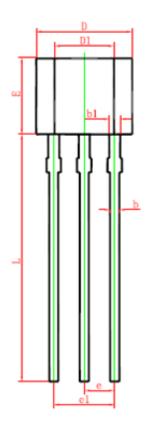


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## 12. Package Information:









Cumhal	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
A	1.420	1.620	0.056	0.064
A1	0.660	0.860	0.026	0.034
b	0.350	0.480	0.014	0.019
b1	0.400	0.550	0.016	0.022
с	0.360	0.510	0.014	0.020
D	3.900	4.100	0.154	0.161
D1	2.280	2.680	0.090	0.106
E	3.050	3.250	0.120	0.128
e	1.270	TYP.	0.050	TYP.
e1	2.440	2.640	0.096	0.104
L	15.100	15.500	0.594	0.610
θ	45° TYP.		45°	TYP.

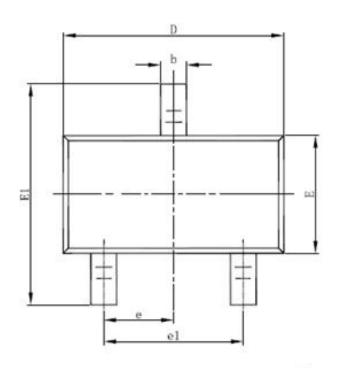


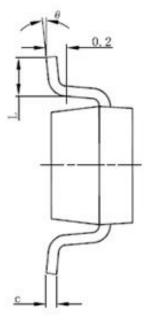
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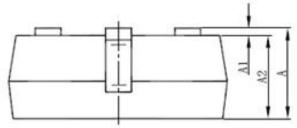
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PACKAGE DESIGNATOR

SOT-23-3L







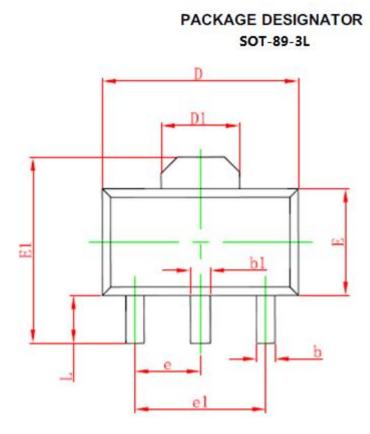
Symbol	Dimensions In	Millimeters	Dimensions	In Inches
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(	BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

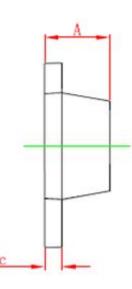




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Symbol	Dimensions In Millimeters		Dimensions In Inche	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
с	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550	REF.	0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060	TYP.
e1	3.000 TYP.		0.118	TYP.
L	0.900	1.200	0.035	0.047



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